MC74VHC74

Dual D-Type Flip-Flop with Set and Reset

The MC74VHC74 is an advanced high speed CMOS D−type flip−flop fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The signal level applied to the D input is transferred to Q output during the positive going transition of the Clock pulse.

Reset ($\overline{RD}$) and Set ($\overline{SD}$) are independent of the Clock (CP) and are accomplished by setting the appropriate input Low.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

Features

- High Speed: f_{max} = 170MHz (Typ) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 2μA (Max) at T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC}
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 5.5 V Operating Range
- Low Noise: V_{OLP} = 0.8 V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance:
  Human Body Model > 2000 V;
  Machine Model > 200 V
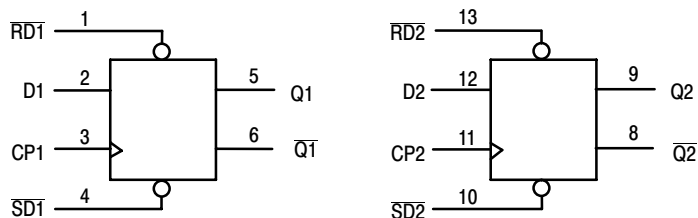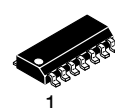- Chip Complexity: 128 FETs or 32 Equivalent Gates
- Pb−Free Packages are Available*
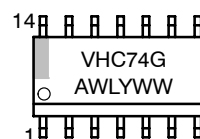
Figure 1. LOGIC DIAGRAM

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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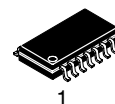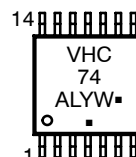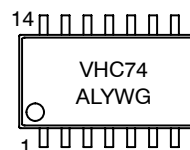
FUNCTION TABLE

Inputs				Outputs	
$\overline{SD}$	$\overline{RD}$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H*	H*
H	H	⤴	H	H	L
H	H	⤴	L	L	H
H	H	L	X	No Change	
H	H	H	X	No Change	
H	H	⤵	X	No Change	

*Both outputs will remain high as long as Set and Reset are low, but the output states are unpredictable if Set and Reset go high simultaneously.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

MC74VHC74

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	-0.5 to $+7.0$	V
V_{in}	DC Input Voltage	-0.5 to $+7.0$	V
V_{out}	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	Input Diode Current	-20	mA
I_{OK}	Output Diode Current	± 20	mA
I_{out}	DC Output Current, per Pin	± 25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	± 50	mA
P_D	Power Dissipation in Still Air, SOIC Packages† TSSOP Package†	500 450	mW
T_{stg}	Storage Temperature	-65 to $+150$	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Derating — SOIC Packages: -7 mW/°C from 65° to 125°C
TSSOP Package: -6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND $\leq$ (V_{in} or V_{out}) $\leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

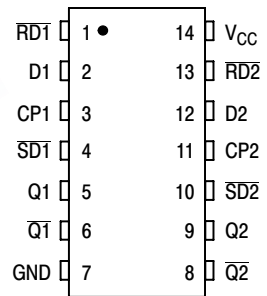| Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		2.0	5.5	V
V_{in}	DC Input Voltage		0	5.5	V
V_{out}	DC Output Voltage		0	V_{CC}	V
T_A	Operating Temperature, All Package Types		-40	$+85$	°C
t_r, t_f	Input Rise and Fall Time	$V_{CC} = 3.3V \pm 0.3V$ $V_{CC} = 5.0V \pm 0.5V$	0 0	100 20	ns/V

$\overline{RD1}$	1 •	14	V_{CC}
D1	2	13	$\overline{RD2}$
CP1	3	12	D2
$\overline{SD1}$	4	11	CP2
Q1	5	10	$\overline{SD2}$
$\overline{Q1}$	6	9	Q2
GND	7	8	$\overline{Q2}$

Figure 2. PIN ASSIGNMENT

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CC} V	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	T_A = −40 to 85°C Min	T_A = −40 to 85°C Max	Unit
V_{IH}	Minimum High–Level Input Voltage		2.0 3.0 to 5.5	1.50 V_{CC} x 0.7			1.50 V_{CC} x 0.7		V
V_{IL}	Maximum Low–Level Input Voltage		2.0 3.0 to 5.5			0.50 V_{CC} x 0.3		0.50 V_{CC} x 0.3	V
V_{OH}	Minimum High–Level Output Voltage	$V_{in} = V_{IH}$ or V_{IL} $I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		$V_{in} = V_{IH}$ or V_{IL} $I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94			2.48 3.80		
V_{OL}	Maximum Low–Level Output Voltage	$V_{in} = V_{IH}$ or V_{IL} $I_{OL} = 50\mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{in} = V_{IH}$ or V_{IL} $I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5			0.36 0.36		0.44 0.44	
I_{in}	Maximum Input Leakage Current	$V_{in} = 5.5V$ or GND	0 to 5.5			± 0.1		± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{in} = V_{CC}$ or GND	5.5			2.0		20.0	μA

MC74VHC74

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ns)

Symbol	Parameter	Test Conditions		$T_A = 25°C$			$T_A = -40$ to $85°C$		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, CP to Q or $\overline{Q}$	$V_{CC} = 3.3 \pm 0.3$V	$C_L = 15$pF $C_L = 50$pF		6.7 9.2	11.9 15.4	1.0 1.0	14.0 17.5	ns
		$V_{CC} = 5.0 \pm 0.5$V	$C_L = 15$pF $C_L = 50$pF		4.6 6.1	7.3 9.3	1.0 1.0	8.5 10.5	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, $\overline{SD}$ or $\overline{RD}$ to Q or $\overline{Q}$	$V_{CC} = 3.3 \pm 0.3$V	$C_L = 15$pF $C_L = 50$pF		7.6 10.1	12.3 15.8	1.0 1.0	14.5 18.0	ns
		$V_{CC} = 5.0 \pm 0.5$V	$C_L = 15$pF $C_L = 50$pF		4.8 6.3	7.7 9.7	1.0 1.0	9.0 11.0	
f_{max}	Maximum Clock Frequency (50% Duty Cycle)	$V_{CC} = 3.3 \pm 0.3$V	$C_L = 15$pF $C_L = 50$pF	80 50	125 75		70 45		MHz
		$V_{CC} = 5.0 \pm 0.5$V	$C_L = 15$pF $C_L = 50$pF	130 90	170 115		110 75		
C_{in}	Maximum Input Capacitance				4	10		10	pF

		Typical @ 25°C, V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance (Note 1)	25	pF

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/2$ (per flip-flop). C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

TIMING REQUIREMENTS (Input $t_r = t_f = 3.0$ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit		Unit
			$T_A = 25°C$	$T_A = -40$ to $85°C$	
t_w	Minimum Pulse Width, CP	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
t_w	Minimum Pulse Width, $\overline{RD}$ or $\overline{SD}$	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
t_{su}	Minimum Setup Time, D to CP	3.3 ± 0.3 5.0 ± 0.5	6.0 5.0	7.0 5.0	ns
t_h	Minimum Hold Time, D to CP	3.3 ± 0.3 5.0 ± 0.5	0.5 0.5	0.5 0.5	ns
t_{rec}	Minimum Recovery Time, $\overline{SD}$ or $\overline{RD}$ to CP	3.3 ± 0.3 5.0 ± 0.5	5.0 3.0	5.0 3.0	ns

ORDERING INFORMATION

Device	Package	Shipping†
MC74VHC74DR2	SOIC–14	2500 Tape & Reel
MC74VHC74DR2G	SOIC–14 (Pb–Free)	2500 Tape & Reel
MC74VHC74DT	TSSOP–14*	96 Units / Rail
MC74VHC74DTG	TSSOP–14*	96 Units / Rail
MC74VHC74DTR2	TSSOP–14*	2500 Tape & Reel
MC74VHC74DTR2G	TSSOP–14*	2500 Tape & Reel
MC74VHC74MEL	SOEIAJ–14	2000 Tape & Reel
MC74VHC74MELG	SOEIAJ–14 (Pb–Free)	2000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
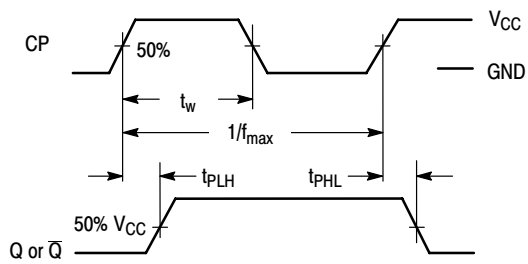
*This package is inherently Pb–Free.

Figure 3.

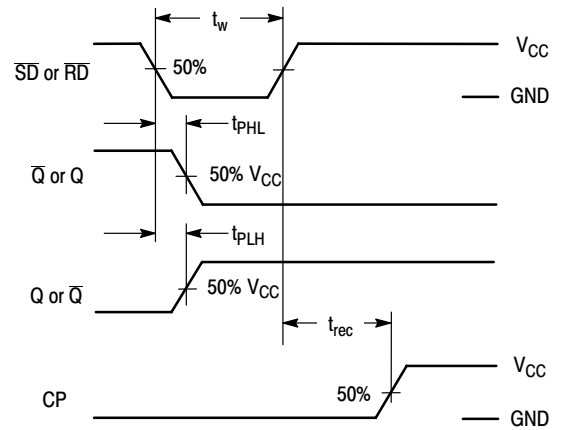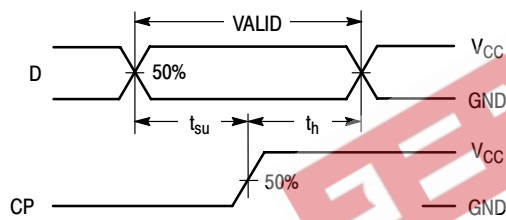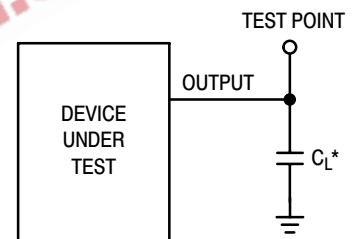**Figure 4.**

Switching Waveforms

Figure 5.

*Includes all probe and jig capacitance

Figure 6.
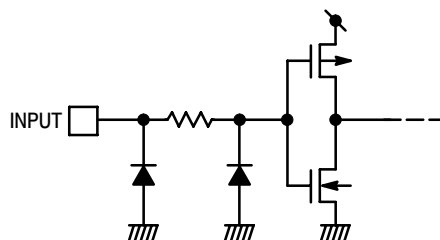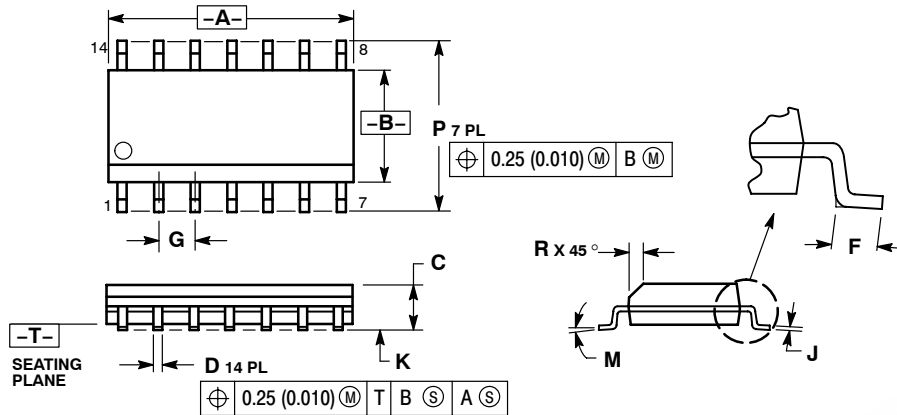

Figure 7. Input Equivalent Circuit

MC74VHC74

PACKAGE DIMENSIONS
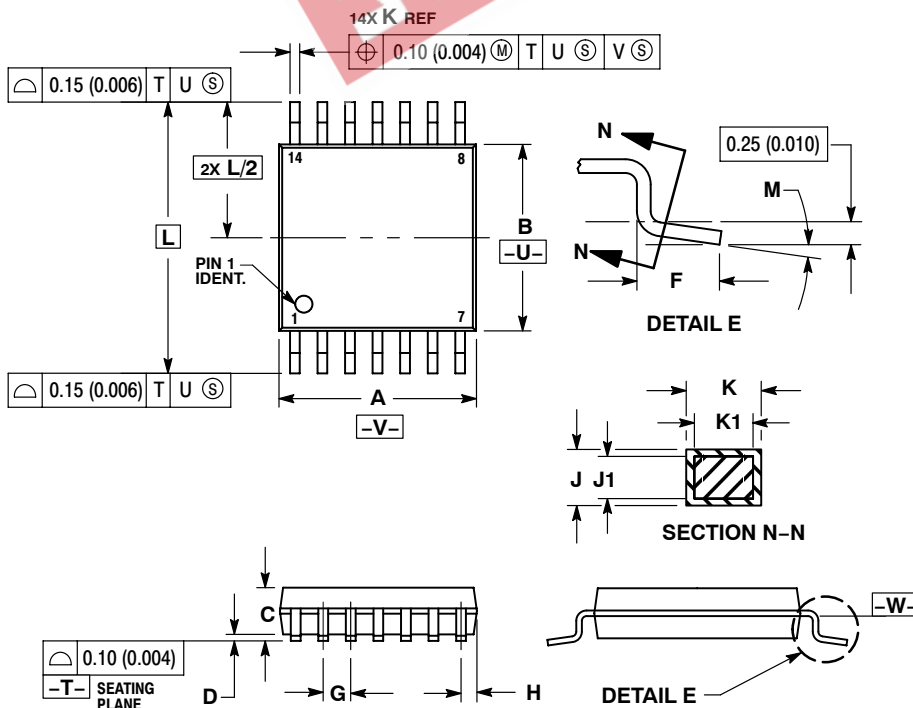
SOIC–14
D SUFFIX
CASE 751A–03
ISSUE G

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

TSSOP–14
DT SUFFIX
CASE 948G–01
ISSUE A

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

MC74VHC74

PACKAGE DIMENSIONS

SOEIAJ−14
M SUFFIX
CASE 965−01
ISSUE A
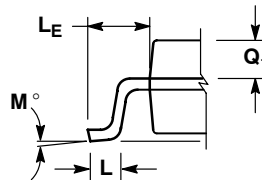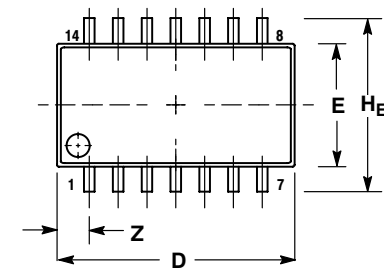
DETAIL P

VIEW P
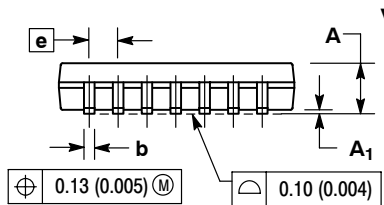
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	---	2.05	---	0.081
A₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.004	0.008
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q₁	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056